



DMP3010LPSQ

P-CHANNEL ENHANCEMENT MODE MOSFET PowerDI

Product Summary

V _{(BR)DSS}	R _{DS(ON)}	I _D T _A = +25°C
-30V	$7.5 m\Omega @ V_{GS} = -10V$	-36A
-301	10mΩ @ V _{GS} = -4.5V	-31A

Description

This new generation 30V P-Channel Enhancement Mode MOSFET is designed to minimize $R_{DS(ON)}$, yet maintain superior switching performance. This device is ideal for use in notebook battery power management and loadswitch.

Applications

- Notebook Battery Power Management
- DC-DC Converters
- Loadswitch

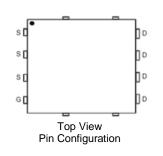
Features

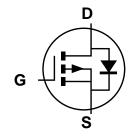
- Thermally Efficient Package Cooler Running Applications
- High Conversion Efficiency
- Low R_{DS(ON)} Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications
- ESD HBM Protected up to 1kV
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Available (Note 4)

Mechanical Data

- Case: PowerDI[®]5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish 100% Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)







Internal Schematic

Ordering Information (Note 5)

Part Number	Qualification	Case	Packaging
DMP3010LPSQ-13	Automotive	PowerDI5060-8	2,500/Tape & Reel

Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

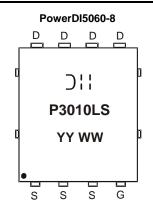
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/quality/product_compliance_definitions/.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.



Marking Information



⊃! = Manufacturer's Marking P3010LS = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 15 = 2015) WW = Week (01 - 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristi	Symbol	Value -30	Unit V		
Drain-Source Voltage	V _{DSS}				
Gate-Source Voltage	V _{GSS}	±20	V		
Continuous Drain Current (Note 8) V_{GS} = 10V	Steady State	T _A = +25°C T _A = +70°C	ID	-36 -29	А
Continuous Drain Current (Note 8) V_{GS} = 4.5V	Steady State	T _A = +25°C T _A = +70°C	ID	-31 -25	А
Continuous Drain Current (Note 7) V_{GS} = 10V	Steady State	T _A = +25°C T _A = +70°C	Ι _D	-14.5 -11.5	А
Pulsed Drain Current (Notes 7 & 10)	I _{DM}	-100	А		
Avalanche Current (Notes 11 & 12)	I _{AS}	-17.5	А		
Avalanche Energy (Notes 11 & 12) L = 1mH			E _{AS}	153	mJ

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	PD	1.26	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 6)	R _{0JA}	97	°C/W
Power Dissipation (Note 7)	PD	2.18	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 7)	R _{0JA}	55	°C/W
Power Dissipation (Note 8)	PD	14.37	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 8)	R _{0JA}	8.7	°C/W
Power Dissipation (Notes 8 & 9)	PD	58.7	W
Thermal Resistance, Junction to Case @T _C = +25°C (Notes 8 & 9)	R _{0JC}	2.13	°C/W
Operating and Storage Temperature Range	TJ, T _{STG}	-55 to +150	°C

6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. 7. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

8. Device mounted on FR-4 PCB with infinite heatsink.

- 9. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.
- 10. Repetitive rating, pulse width limited by junction temperature, 10µs pulse, duty cycle = 1%.

11. I_{AS} and E_{AS} rating are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

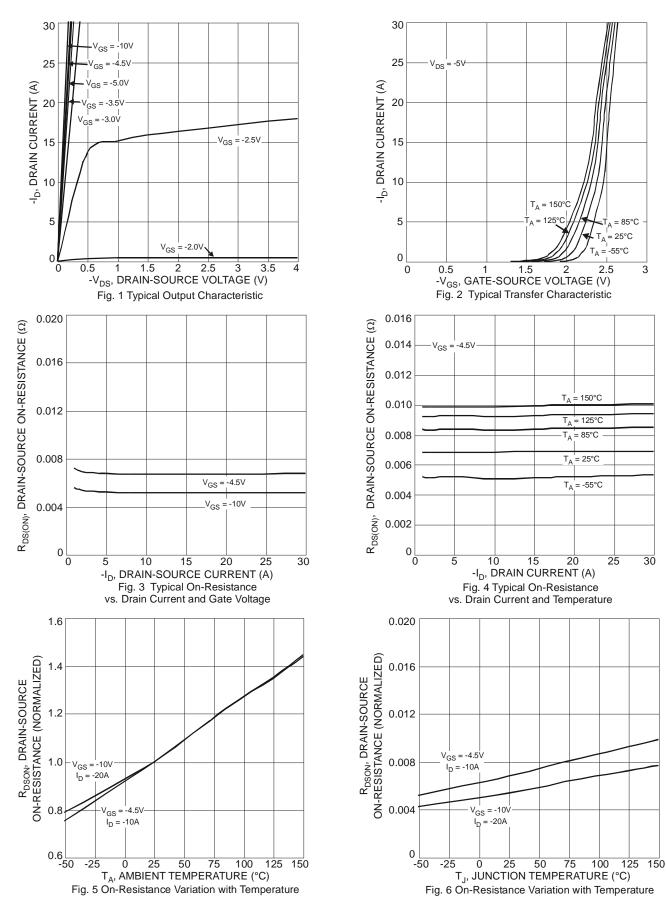
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Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 12)			•		r	-	
Drain-Source Breakdown Voltage	BV _{DSS}	-30	—	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	—	—	-1	μA	$V_{DS} = -30V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	—	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 12)							
Gate Threshold Voltage	V _{GS(th)}	-1.1	-1.6	-2.1	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$	
Static Drain-Source On-Resistance	Brayaw	—	5.7	7.5	mΩ	$V_{GS} = -10V, I_D = -10A$	
	R _{DS(ON)}	—	7.2	10	11152	$V_{GS} = -4.5V, I_D = -10A$	
Forward Transfer Admittance	Y _{fs}	_	30	_	S	$V_{DS} = -15V, I_D = -10A$	
Diode Forward Voltage	V _{SD}	_	-0.65	-1	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 13)							
Input Capacitance	Ciss	—	6,234	—	pF	−V _{DS} = 15V, V _{GS} = 0V, −f = 1MHz	
Output Capacitance	Coss	_	1,500	—	pF		
Reverse Transfer Capacitance	C _{rss}	_	774	—	pF		
Gate Resistance	Rg	—	1.28	—	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = -10V)	Qg	_	126.2	—	nC	V _{DS} = -15V, I _D = -10A	
Total Gate Charge (V _{GS} = -4.5V)	Qg	—	59.2	—	nC	V _{DS} = -15V, V _{GS} = -4.5V, I _D = -10A	
Gate-Source Charge	Q _{gs}	_	16.1	—	nC		
Gate-Drain Charge	Q _{gd}	_	15.7	—	nC		
Turn-On Delay Time	t _{D(on)}	_	11.4	—	ns		
Turn-On Rise Time	tr	_	9.4	—	ns	$V_{DS} = -15V, V_{GEN} = -10V,$	
Turn-Off Delay Time	t _{D(off)}	—	260.7	—	ns	$R_G = 6\Omega, I_D = -1A$	
Turn-Off Fall Time	t _f	—	99.3		ns	7	

 Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:

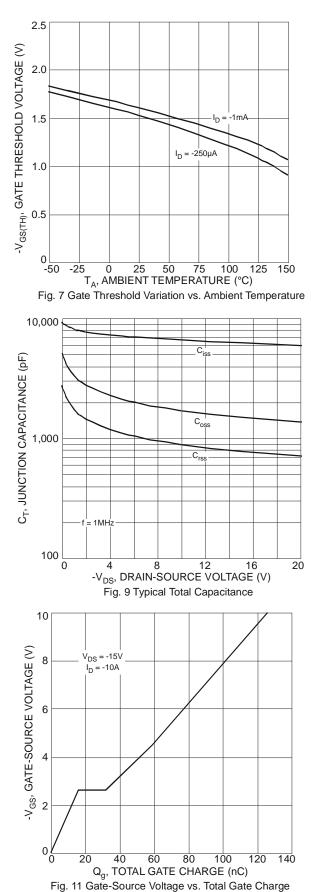
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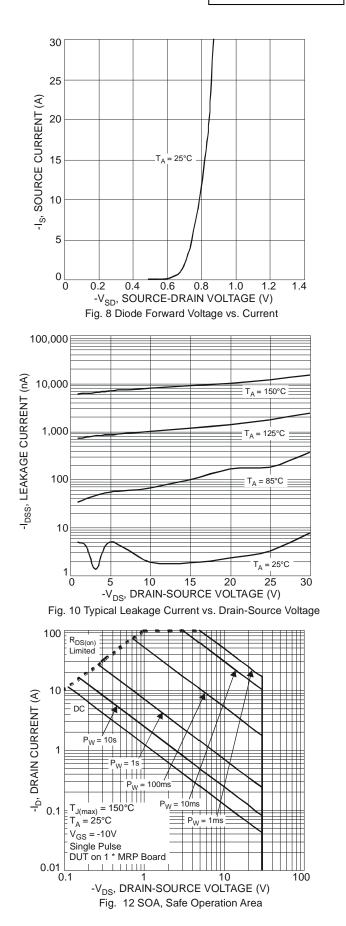
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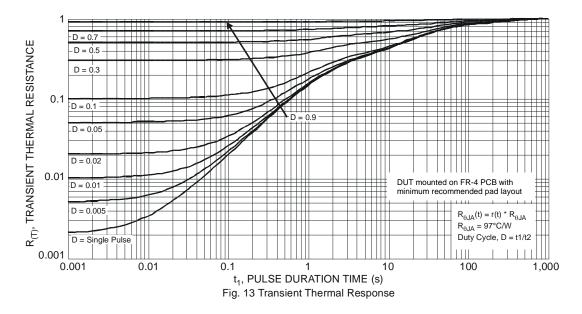








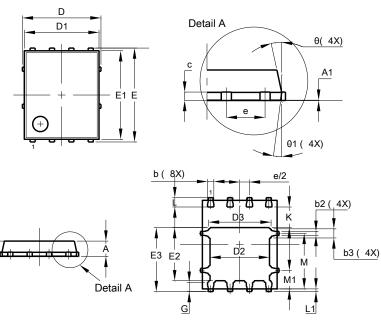






Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



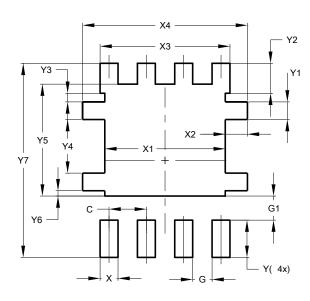
PowerDI5060-8					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
c	0.230	0.330	0.277		
D	-	5.15 BSC	;		
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
E	6.15 BSC				
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е	1.27 BSC				
G	0.51	0.71	0.61		
K	0.51	-	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

PowerDI5060-8

PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610



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